### High Voltage Low Power Consumption LDO

### **MD85XX Series**

### **CMOS Voltage Regulator With ON/OFF Switch**

#### 300mA



MD85XX is a high voltage (up to 40V) ultra-low quiescent current low dropout voltage regulator (LDO) manufactured in CMOS processes. It can deliver up to 300mA of current while consuming only 1.5uA of quiescent current. It consists of a reference voltage generator, an error amplifier, a current foldback circuit, and a phase compensation circuit plus a driver transistor. The MD85XX is designed specifically for applications where very-low  $I_Q$  is a critical parameter. This device

maintains low quiescent current consumption even in dropout mode to further increase the battery life. When in shutdown or disabled mode, the device consumes less than 100-nA  $I_Q$  even with input voltage of 40V that helps increase the shelf life of the battery.

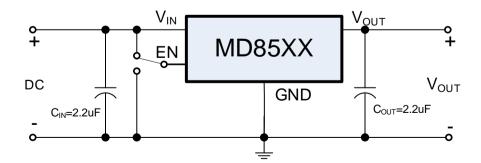
#### Features

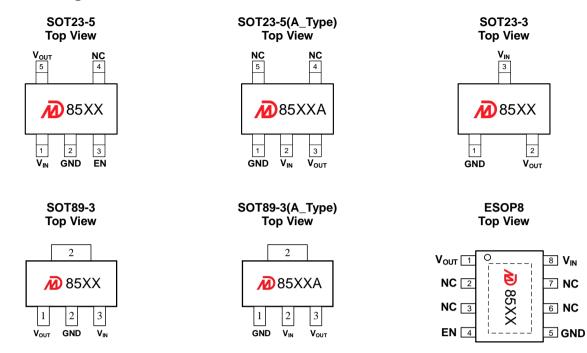
- Ultra-low Quiescent Current: 1.5uA
- Maximum Input Voltage: 40V
- Output Voltage Highly Accurate: ±2%
- Maximum Output Current: 300mA
- Dropout Voltage: 4mV@Iout=1mA
- Temperature Stability: ±50ppm/℃
- ON/OFF Logic = Enable High
- Protections Circuits: Current Limiter, Short Circuit, Foldback, Thermal shutdown
- Output Capacitor: Low ESR Ceramic Capacitor Compatible

#### Applications

- Smart wearer
- Long-life battery-powered devices
- Portable mobile devices, such as mobile phones, cameras, and so on
- · Wireless communication equipment

#### Typical Applications





#### Pin Configuration and Functions

#### **Pin Functions**

NAME	DESCRIPTION
V <sub>IN</sub>	Power Input Pin.
EN	Enable pin. Drive this pin high to enable the device. Drive this pin low to put the device into low current shutdown.
Vout	Regulated output voltage pin
GND	Ground
Thermal pad	The thermal pad is electrically connected to the GND node. Connect this pad to the GND plane for improved thermal performance.
NC	No internal connection

#### Product Selections

Product Name	Vout (V)	Package	Ordering Name	Marking	Package Information	
MD8530	3.0	SOT23-5L	MD85E30QC3	₱ 8530		
MD8533	3.3	SOT23-5L	MD85E33QC3	₱ 8533		
MD8536	3.6	SOT23-5L	MD85E36QC3	₱ 8536		
MD8550	MD8550 5.0		MD85E50QC3	₱ 8550	Tape and Reel,	
MD8530A	3.0	SOT23-5L	MD85A30QC3	₩8530A	3000pcs	
MD8533A	3.3	SOT23-5L	MD85A33QC3	₩8533A		
MD8536A	3.6	SOT23-5L	MD85A36QC3	₩8536A		
MD8550A	5.0	SOT23-5L	MD85A50QC3	₩8550A		
MD8530	3.0	SOT23-3L	MD85E30QA3	AD 8530		
MD8533	3.3	SOT23-3L	MD85E33QA3	₱ 8533	Tape and Reel,	
MD8536	MD8536 3.6		MD85E36QA3	<b>№</b> 8536	3000pcs	
MD8550	5.0	SOT23-3L	MD85E50QA3	A 8550		

MD8530	3.0	SOT89-3L	MD85E30PA1	108530	
MD8533	3.3	SOT89-3L	MD85E33PA1	₱8533	
MD8536	3.6	SOT89-3L	MD85E36PA1	₱8536	
MD8550	5.0	SOT89-3L	MD85E50PA1	₱8550	Tape and Reel,
MD8553	5.3	SOT89-3L	MD85E53PA1	₱8553	1000pcs
MD8557	5.7	SOT89-3L	MD85E57PA1	₱ 8557	
MD85C0	12.0	SOT89-3L	MD85EC0PA1	₩85C0	
MD85F0	15.0	SOT89-3L	MD85EF0PA1	285F0	
MD8530A	3.0	SOT89-3L	MD85A30PA1	₩8530A	
MD8533A	3.3	SOT89-3L	MD85A33PA1	₩8533A	
MD8536A	3.6	SOT89-3L	MD85A36PA1	₩8536A	Tape and Reel,
MD8550A	5.0	SOT89-3L	MD85A50PA1	₩8550A	1000pcs
MD85C0A	12.0	SOT89-3L	MD85AC0PA1	₩85C0A	
MD85F0A	15.0	SOT89-3L	MD85EF0PA1	285F0A	
MD8533	3.3	ESOP8	MD85E33SF4	₱8533	
MD8550	5.0	ESOP8	MD85E50SF4	₱ 8550	Tape and Reel,
MD85C0	MD85C0 12.0		MD85EC0SF4	₩85C0	4000pcs
MD85F0	15.0	ESOP8	MD85EF0SF4	₩85F0	

Notes:

1\* Customer can request to customize the output voltage ranged from 1.2V to 15V if desired voltage is not found in the selections.

2\* Customer can request customization of package choice.

3\* Please pay attention to the MARKING of the product package type.

Absolute Maximum Ratings (	Unless otherwise indicated: $T_a=25^{\circ}C$ )
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Absolute maximum Ratings (Onless otherwise indicated. Ta=23 C)								
PARAMETER	SYMBOL	RATINGS		UNITS				
Input Voltage	V <sub>IN</sub>	-0.3 ~ 45		V				
Output Voltage	Vout	Vss-0.3 ~ VIN+0.3V		V				
		SOT23-5 250						
Dower Dissinction	D-	SOT23-3	250	m)\//				
Power Dissipation	PD	ESOP8	1800	mW				
		SOT89-3	1000					
Thermal Resistance	R <sub>0JB</sub> <sup>(1)</sup>	SOT23-5 180						
		SOT23-3	200	°C/W				
		ESOP8	80	C/VV				
		SOT89-3	100					
Operating Ambient Temperature	T <sub>opr</sub>	-40 ~ +85		Ĉ				
Storage Temperature	T <sub>stg</sub>	-40 ~ +125						
ESD Protection	ESD HBM	5000		V				

Note: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device.

<sup>(1)</sup> Mounted on JEDEC standard 4layer (2s2p) PCB test board

#### Notes on Use

Input Capacitor ( $C_{IN}$ ): 2.2 $\mu$ F above Output Capacitor ( $C_{OUT}$ ): 2.2 $\mu$ F above

### **Electrical Characteristics**

PARAMETER	SYMBOL	CONDITIONS			MIN.	TYP.	MAX.	UNIT	
Output Voltage*1	V <sub>OUT(S)</sub>	$V_{IN}=V_{OUT(S)}+2V$ , $I_{OUT}=1mA$		V <sub>OUT(S)</sub> × 0.98	V <sub>OUT(S)</sub>	V <sub>OUT(S)</sub> × 1.02	V		
	N.	$V_{EN}=V_{IN}, V_{OUT(S)}=3.3V$ $I_{OUT}=1mA$			4	8	- mV		
Dropout Voltage*2	Vdrop	V <sub>EN</sub> =V <sub>IN</sub> , V <sub>OUT(S)</sub> =3.3V I <sub>OUT</sub> =300mA			1200	1800			
Line Regulation	$\frac{\Delta V_{OUT}}{\Delta V_{IN} \bullet V_{OUT(s)}}$	V <sub>OUT(S)</sub> +2V≤V <sub>IN</sub> ≤40V I <sub>OUT</sub> =1mA				0.01	0.02	%/V	
Load Degulation		V <sub>IN</sub> = V <sub>OUT(S)</sub> +2V V <sub>OUT(S)</sub> ≤5.3V			20	40			
Load Regulation	$\Delta V_{OUT2}$	1mA≤I <sub>OUT</sub> ≤3	00mA	V <sub>OUT(S)</sub> >5.3V		50	80	mV	
Temperature Stability	$\frac{\Delta V_{OUT}}{\Delta T_a \bullet V_{OUT(s)}}$	V <sub>IN</sub> = V <sub>OUT(S)</sub> +2V, I <sub>OUT</sub> =10mA -40°C≤T <sub>a</sub> ≤125°C				±50		<b>ppm/</b> ℃	
	GND		Ņ	Vout(s)<3.0V	0.8	1.2	2		
GND Current		no load	3.0	)≤V <sub>OUT(S)</sub> ≤5.3V	1	1.5	2.5		
(V <sub>EN</sub> =V <sub>IN</sub> )			١	Vout(s)>5.3V	1.5	2.3	3.5		
		I <sub>OUT</sub> =100mA				420		uA	
Shutdown Current (EN=0)	I <sub>SHUT</sub>	V <sub>IN</sub> =40.0V, V <sub>EN</sub> =0			0.1	1			
Input Voltage	V <sub>IN</sub>			2.2		40	V		
Maximum Output Current	IOUTMAX				300	350			
Current Limit*3	ILIM	V <sub>IN</sub> = V <sub>OUT(S)</sub> +2V, V <sub>OUT</sub> = 0.95 ×V <sub>OUT(S)</sub>		350	550		mA		
Short Circuit Current	ISHORT	V <sub>IN</sub> =V <sub>EN</sub> =V <sub>OUT(S)</sub> +2.0V V <sub>OUT</sub> =0V			65				
	tion PSRR	f=100Hz, I <sub>OUT</sub> =10mA			79				
Power Supply Rejection		f=1kHz, I <sub>OUT</sub> =10mA			62		dB		
Ratio		f=10kHz, I <sub>OUT</sub> =10mA			48		uВ		
		f=100kHz, I <sub>OUT</sub> =10mA			40				
EN 'H' Level Voltage	V <sub>ENH</sub>			1.5		40.0	v		
EN 'L' Level Voltage	VENL			0		0.6	v		
EN 'H' Level Current	IENH	Vin=40V, Ven=Vin		-0.1		0.1	uA		
EN 'L' Level Voltage	IENL	Vin=40V, Ven=0		-0.1		0.1	u.,		
Over Temperature Protection	OTP	I <sub>OUT</sub> =1mA			170		°C		

MD85XX Series (Unless otherwise indicated:  $T_a=25^{\circ}C$ )

Notes:

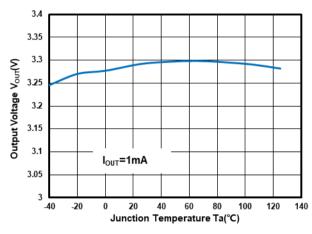
1.  $V_{OUT(S)}$ : Output voltage when  $V_{IN}=V_{OUT}+2V$ ,  $I_{OUT}=1$  mA.

2.  $V_{DROP}=V_{IN1}$  -  $(V_{OUT(S)} \times 0.98)$  where  $V_{IN1}$  is the input voltage when  $V_{OUT} = V_{OUT(S)} \times 0.98$ .

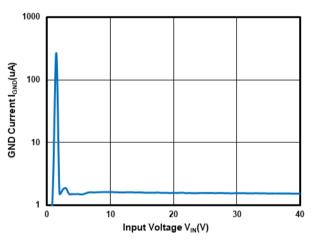
3. ILIM: Output current when VIN=VOUT(S)+2V and VOUT =  $0.95^*V_{OUT(S)}$ .

### Typical Performance Characteristics

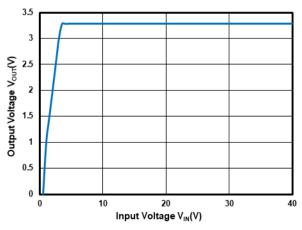
Test Conditions:  $V_{IN}=V_{OUT}+2.0V$ ,  $C_{IN}=2.2\mu$ F,  $C_{OUT}=2.2\mu$ F, Ta=25°C, unless otherwise indicated.

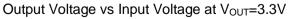


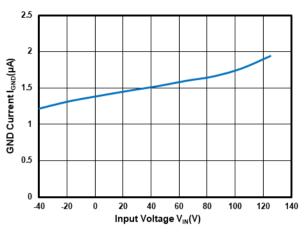
Output Voltage vs Temperature at  $V_{OUT}$ =3.3V



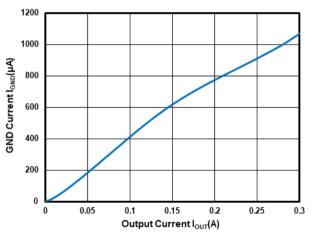
GND Current vs Input Voltage at Vout=3.3V



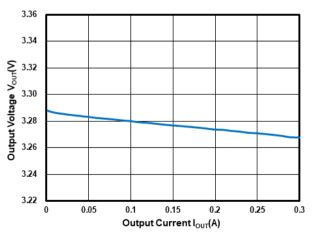




GND Current vs Temperature at  $V_{OUT}$ =3.3V



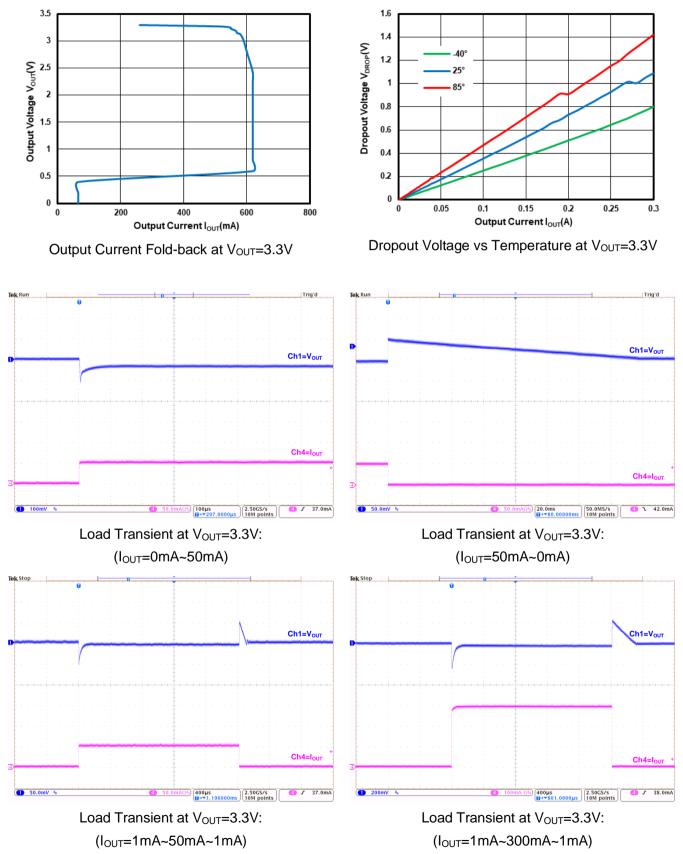
GND Current vs Output Current at Vout=3.3V



Output Voltage vs Output Current at VOUT=3.3V

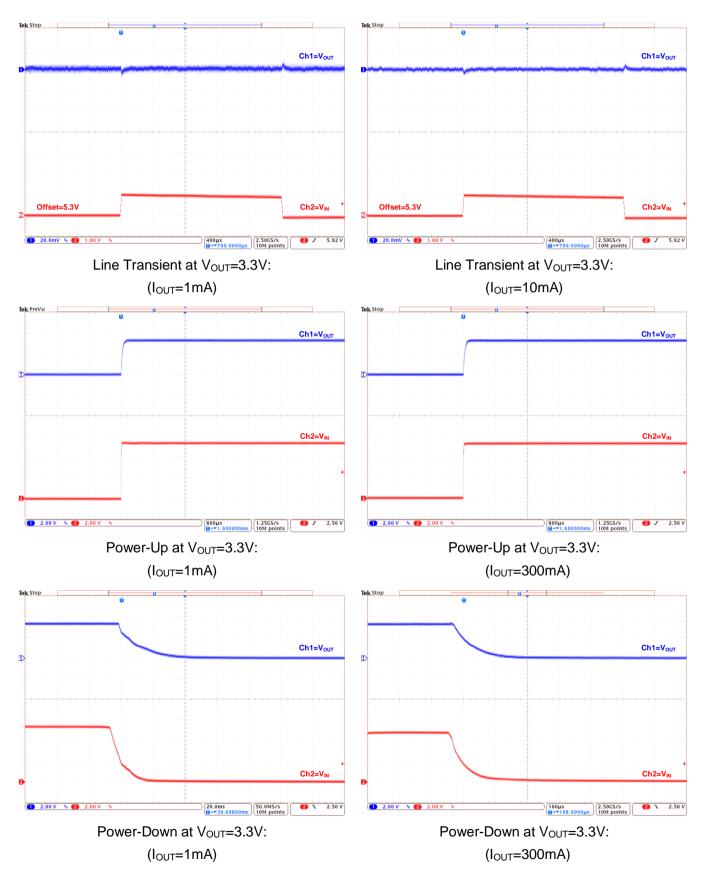
## Typical Performance Characteristics (Continued)

Test Conditions:  $V_{IN}=V_{OUT}+2.0V$ ,  $C_{IN}=2.2\mu$ F,  $C_{OUT}=2.2\mu$ F, unless otherwise indicated.



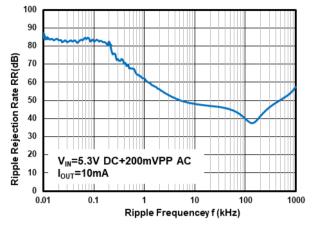
## Typical Performance Characteristics (Continued)

Test Conditions:  $V_{IN}=V_{OUT}+2.0V$ ,  $C_{IN}=2.2\mu$ F,  $C_{OUT}=2.2\mu$ F,  $Ta=25^{\circ}$ C, unless otherwise indicated.



### Typical Performance Characteristics (Continued)

Test Conditions: V\_IN=V\_OUT+2.0V, C\_IN=2.2 \mu F, C\_OUT=2.2 \mu F, Ta=25  $^\circ \rm C$ , unless otherwise indicated.

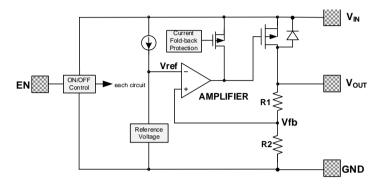


Power Supply Rejection Ratio at  $V_{OUT}=3.3V$ 

### Operational Explanation

### 1. Output voltage control

The voltage divided by resistors R1 and R2 is compared with the internal reference voltage by the error amplifier. The amplifier output then drives the P-channel MOSFET connected to the  $V_{OUT}$  pin. The output voltage at the  $V_{OUT}$  pin is regulated by this negative feedback system. The current limit circuit and short protect circuit operate in relation to output current level. Further, the IC's internal circuitry can be in operation or shutdown modes controlled by the CE pin's signal.



#### 2. Pass transistor

The pass transistor with low turn-on resistance used in MD85XX is a P-channel MOSFET. If the potential on  $V_{OUT}$  pin is higher than VIN, it is possible that IC will be destroyed due to reverse current which is caused by parasitic diodes between  $V_{IN}$  and  $V_{OUT}$ . Therefore, the  $V_{OUT}$  pin potential exceeds  $V_{IN}$ +0.3V is not allowed.

3. Current foldback, short circuit protection and over temperature protection

The MD85XX series includes a combination of a fixed current limiter circuit and a foldback circuit, which aid the operations of the current limiter and circuit protection. When the load current reaches the current limit level, the fixed current limiter circuit operates and output voltage drops. As a result of this drop in output voltage, the foldback circuit operates, output voltage drops further and output current decreases. The short circuit current is about 65mA (typical value). This design can prevent the chip be damaged due to over temperature, moreover, the heat dissipation is limited by the package type.

Special attention should be paid to that the product of the dropout voltage on the chip and the output current must be smaller than the heat dissipation. If power consumption on the chip is more than the heat dissipation, OTP will protect the chip from damaging due to over temperature.

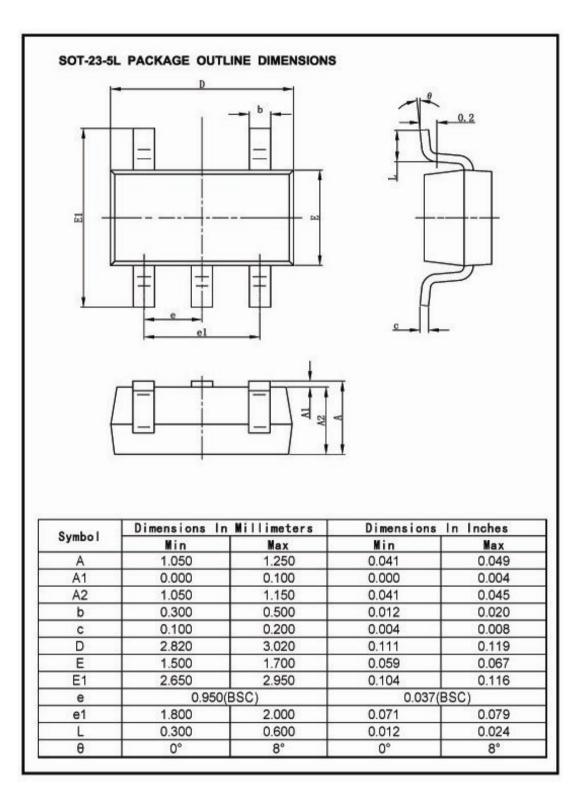
#### ■ Notes:

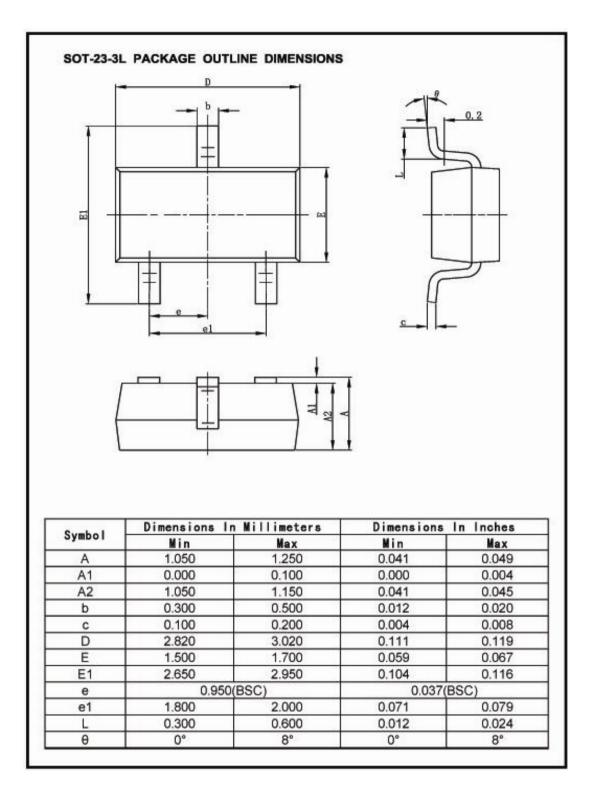
1. The input and output capacitors should be placed as close as possible to the IC.

2. If the impedance of the power supply is high, which is caused by forgetting installing input capacitor or installing too small value capacitor, the oscillation may occur.

3. Pay attention to the operation conditions of input and output voltage and load current, such that the power consumption in the IC should not exceed the allowable power consumption of the package even though the chip has short circuit protection.4. IC has a built-in anti-static protection (ESD) circuit, but please do not add excessive stress to the IC.

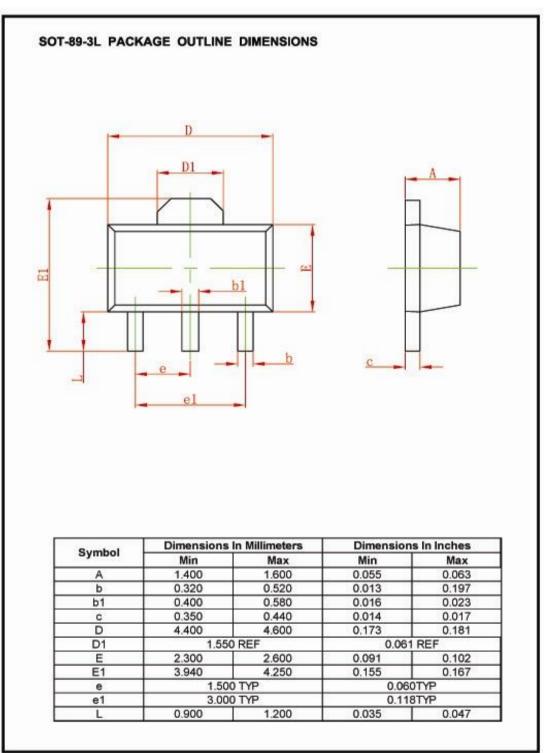
### Packaging Information

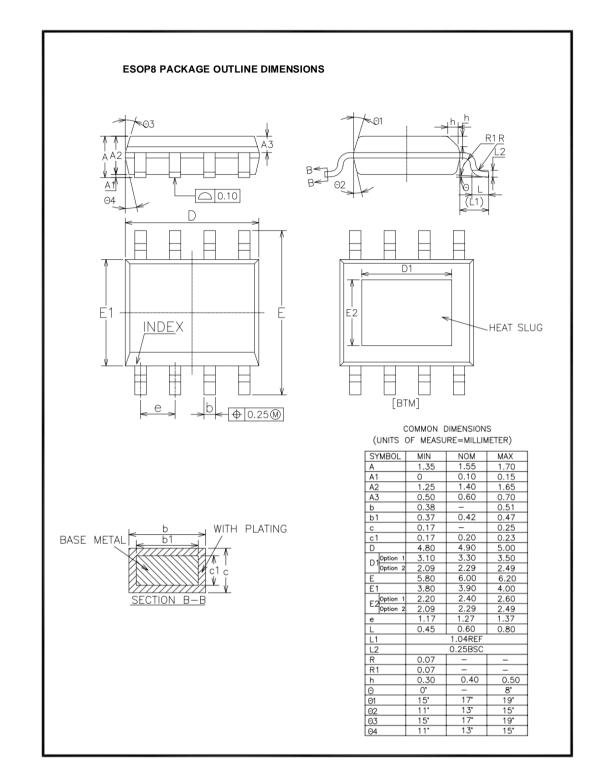




### Packaging Information (Continued)







### Packaging Information (Continued)

For the newest datasheet, please see the website: Version V1.0: 20200915

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